2SB1071, 2SB1071A

Silicon PNP epitaxial planar type

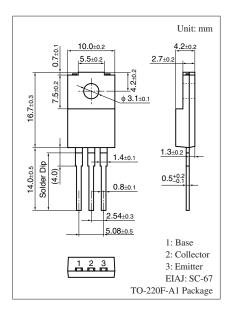
For low-voltage switching

■ Features

- Low collector-emitter saturation voltage V_{CE(sat)}
- High-speed switching
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage	2SB1071	V_{CBO}	-40	V
(Emitter open)	2SB1071A		-50	
Collector-emitter voltage	2SB1071	V _{CEO}	-20	V
(Base open)	2SB1071A		-40	
Emitter-base voltage (Col	V_{EBO}	-5	V	
Collector current	I_C	-4	A	
Peak collector current	I_{CP}	-8	A	
Collector power dissipation	P _C	25	W	
	$T_a = 25$ °C		2	
Junction temperature	T _j	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	



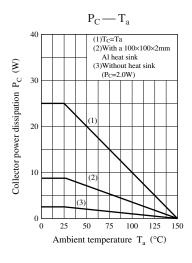
■ Electrical Characteristics $T_C = 25$ ° $C \pm 3$ °C

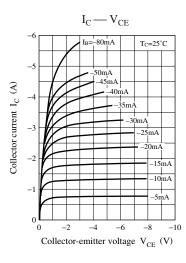
Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage	2SB1071	V _{CEO}	$I_C = -10 \text{ mA}, I_B = 0$	-20			V
(Base open)	2SB1071A			-40			
Collector-base cutoff	2SB1071	I_{CBO}	$V_{CB} = -40 \text{ V}, I_E = 0$			-50	μΑ
current (Emitter open)	2SB1071A		$V_{CB} = -50 \text{ V}, I_E = 0$			-50	
Emitter-base cutoff current (Col	lector open)	I_{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$			-50	μΑ
Forward current transfer rat	io	h _{FE1}	$V_{CE} = -2 \text{ V}, I_{C} = -0.1 \text{ A}$	45			_
		h _{FE2} *	$V_{CE} = -2 \text{ V}, I_{C} = -1 \text{ A}$	60		260	
Collector-emitter saturation	voltage	V _{CE(sat)}	$I_C = -2 A, I_B = -0.1 A$			- 0.5	V
Base-emitter saturation volt	age	V _{BE(sat)}	$I_C = -2 A, I_B = -0.1 A$			-1.5	V
Transition frequency		f_T	$V_{CE} = -5 \text{ V}, I_{C} = -0.5 \text{ A}, f = 10 \text{ MHz}$		150		MHz
Turn-on time		t _{on}	$I_C = -2 A, I_{B1} = -0.2 A, I_{B2} = 0.2 A$		0.3		μs
Storage time	·	t _{stg}	$V_{CC} = -20 \text{ V}$		0.4		μs
Fall time		t _f			0.1		μs

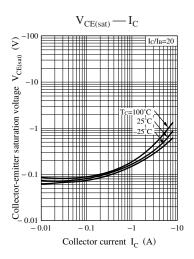
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

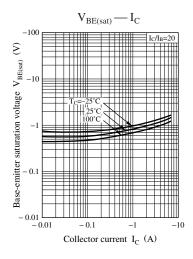
2. *: Rank classification

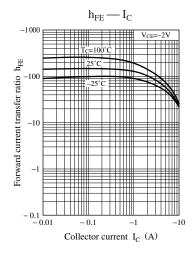
Rank	R	Q	Р	
h _{FE2}	60 to 120	90 to 180	130 to 260	

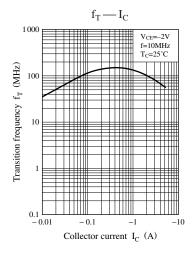


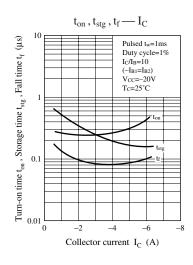


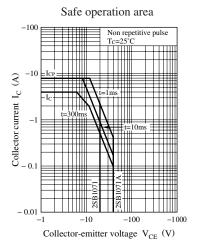




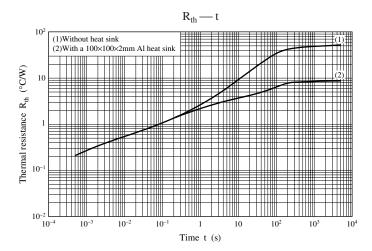








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